L Number	Hits	Search Text	DB	Time stamp
1	0	(tube near3 emolat\$) and heat	USPAT;	2004/01/08 14:42
			EPO; JPO;	
1			DERWENT;	
			USOCR	
2	60445	(transistor or FET) and heat	USPAT;	2004/01/08 16:44
			EPO; JPO;	1
1			DERWENT;	
			USOCR	
3	1519	(transistor or FET) and (heat adj source)	USPAT;	2004/01/08 14:59
			EPO; JPO;	
i			DERWENT;	
			USOCR	
4	25	330/\$.ccls. and ((transistor or FET) and (heat adj	USPAT;	2004/01/08 14:56
		source))	EPO; JPO;	
			DERWENT;	
			USOCR	
5	10	(330/\$.ccls. and ((transistor or FET) and (heat adj	USPAT;	2004/01/08 14:56
		source))) and audio	EPO; JPO;	
			DERWENT;	
			USOCR	
7	1	(381/\$.ccls. and ((transistor or FET) and (heat adj	USPAT;	2004/01/08 14:56
		source))) and audio	EPO; JPO;	!
:			DERWENT;	
			USOCR	
6	4	381/\$.ccls. and ((transistor or FET) and (heat adj	USPAT;	2004/01/08 14:57
		source))	EPO; JPO;	
			DERWENT;	
			USOCR	
8	4	381/\$.ccls. and (transistor or FET) and (heat adj	USPAT;	2004/01/08 16:45
		source)	EPO; JPO;	
			DERWENT;	
			USOCR	
9	1	381/111.ccls. and (heat adj source)	USPAT;	2004/01/08 15:35
			EPO; JPO;	·
			DERWENT;	1
			USOCR	
10	1	381/120.ccls. and (heat adj source)	USPAT;	2004/01/08 16:15
			EPO; JPO;	
			DERWENT;	
			USOCR	
11	3	330/256.ccls. and (heat adj source)	USPAT;	2004/01/08 16:16
Ì			EPO; JPO;	
			DERWENT;	
Y			USOCR	
12	8	330/289.ccls. and (heat adj source)	USPAT;	2004/01/08 16:19
			EPO; JPO;	
			DERWENT;	
			USOCR	
13	303	audio adj signal adj path	USPAT;	2004/01/08 16:19
			EPO; JPO;	
		i	DERWENT;	
	_		USOCR	
14	8	(330/289.ccls. and (heat adj source)) and (heat adj	USPAT;	2004/01/08 16:22
į		source)	EPO; JPO;	
			DERWENT;	
			USOCR	
15	1	"3882728".PN.	USPAT	2004/01/08 16:21
16	2	5977832.URPN.	USPAT	2004/01/08 16:21
17	4673	"113" and (heat adj source)	USPAT;	2004/01/08 16:23
İ			EPO; JPO;	
1		!	DERWENT;	
1			USOCR	1

18	2	(audio adj signal adj path) and (heat adj source)	USPAT; EPO; JPO;	2004/01/08 16:35
			DERWENT;	
			USOCR	
19	358	solid adj state adj component	USPAT;	2004/01/08 16:24
			EPO; JPO;	
			DERWENT;	
			USOCR	
20	126	(solid adj state adj component) and (heat or heated)	USPAT;	2004/01/08 16:24
			EPO; JPO;	
			DERWENT;	
	1		USOCR	
21	13	(solid adj state adj component) same (heat or heated)	USPAT;	2004/01/08 16:28
		same temperature	EPO; JPO;	
			DERWENT;	
			USOCR	
22	3	(solid adj state adj component) with (heat or heated)	USPAT;	2004/01/08 16:28
		with temperature	EPO; JPO;	
			DERWENT;	
			USOCR	
23	303	(audio adj signal adj path) and (audio or sound)	USPAT;	2004/01/08 16:29
20	000	(addio daj signar daj padi) dila (addio or sound)	EPO; JPO;	2004/01/00 10:25
			DERWENT;	
1			USOCR	
24	51	(audio adj signal adj path) and enhanc\$4	USPAT;	2004/01/08 16:29
24	31	(audio adj signal adj patil) alid elinalico4	1	2004/01/06 10.29
ı			EPO; JPO;	
			DERWENT;	
0.5	_	//	USOCR	0004/04/00 46:05
25	5	((audio adj signal adj path) and enhanc\$4) and (heat	USPAT;	2004/01/08 16:35
		or heated or heater or heating)	EPO; JPO;	
			DERWENT;	
		(4 - 12 - 12 - 1 - 12 - 14 - 14 - 14 - 14	USOCR	0004/04/00 40 04
26	2	((audio adj signal adj path) and enhanc\$4) and (heat	USPAT;	2004/01/08 16:34
		adj source)	EPO; JPO;	
			DERWENT;	
			USOCR	
27	0	audio adj sound adj enhancer	USPAT;	2004/01/08 16:35
			EPO; JPO;	
	1		DERWENT;	
			USOCR	
29	2	(audio near3 enhancer) and (heat adj source)	USPAT;	2004/01/08 16:39
			EPO; JPO;	
		İ	DERWENT;	'
			USOCR	
30	2	(USPAT;	2004/01/08 17:12
		or heating)	EPO; JPO;	
	1		DERWENT;	
			USOCR	
28	17	audio near3 enhancer	USPAT;	2004/01/08 16:38
			EPO; JPO;	1
			DERWENT;	
			USOCR	
31	1449	audio near3 enhanc\$4	USPAT;	2004/01/08 16:38
1			EPO; JPO;	
	į.		DERWENT;	
			USOCR	
32	2	(audio near3 enhanc\$4) and (heat adj source)		2004/01/08 17:13
32	2	(audio near3 enhanc\$4) and (heat adj source)	USPAT;	2004/01/08 17:13
32	2	(audio near3 enhanc\$4) and (heat adj source)		2004/01/08 17:13
32	2	(audio near3 enhanc\$4) and (heat adj source)	USPAT; EPO; JPO; DERWENT;	2004/01/08 17:13
			USPAT; EPO; JPO; DERWENT; USOCR	
32	4144216	(audio near3 enhanc\$4) and (heat adj source) 31and (heat or heated or heater or heating)	USPAT; EPO; JPO; DERWENT; USOCR USPAT;	2004/01/08 17:13
			USPAT; EPO; JPO; DERWENT; USOCR	

	(audio near3 enhanc\$4) and ((transistor or FET) and heat)	USPAT; EPO; JPO;	2004/01/08 16:39
:	neary	DERWENT;	
23366	(transistor or FET) same heat	USPAT; EPO; JPO;	2004/01/08 16:44
		DERWENT; USOCR	
1085	(transistor or FET) near heat	EPO; JPO;	2004/01/08 16:44
0	(audia near) anhang\$4) and ((transistor or EET) near	USOCR	2004/01/08 16:44
	heat)	EPO; JPO;	2004/01/08 10:44
. 6	(audio pear3 enhanc\$4) and ((transistor or FFT) same	USOCR	2004/01/08 16:44
	heat)	EPO; JPO;	2004/01/05 10:44
1519	(transistor or FET) and (heat adj source)	USOCR USPAT;	2004/01/08 17:07
	-	EPO; JPO; DERWENT;	
0	(audio near3 enhanc\$4) and ((transistor or FET) and	USOCR USPAT;	2004/01/08 16:49
	(heat adj source))	EPO; JPO; DERWENT;	!
70210	differential adj amplifier	USPAT;	2004/01/08 17:00
		DERWENT;	
99	(USPAT;	2004/01/08 16:53
		DERWENT; USOCR	
32	((differential adj amplifier) and ((transistor or FET) and (heat adj source))) and (audio or sound or enhanc\$4)	USPAT; EPO; JPO; DERWENT:	2004/01/08 16:53
40	(////	USOCR	0004104100405
10	((differential adj ampliffer) and ((transistor of FET) and (heat adj source))) and (audio or sound)	EPO; JPO; DERWENT;	2004/01/08 16:53
31	differential adj amplifier adj component\$	USPAT;	2004/01/08 17:01
		DERWENT;	
0	(differential adj amplifier adj component\$) and (dual adj transistor\$4)	USPAT;	2004/01/08 17:11
		DERWENT; USOCR	
23	(differential adj amplifier adj component\$) and transistor\$4	USPAT; EPO; JPO;	2004/01/08 17:03
		USOCR	
1950	sound near enhanc\$4	EPO; JPO;	2004/01/08 17:03
•	(sound poor ophono\$4) and (/differential adj annulfier	USOCR	2004/04/09 47:00
	adj component\$) and transistor\$4)	EPO; JPO; DERWENT;	2004/01/08 17:03
	1085 0 6 1519 0 70210 99 32 16 31	(udio near3 enhanc\$4) and ((transistor or FET) near heat) (audio near3 enhanc\$4) and ((transistor or FET) same heat) (transistor or FET) and (heat adj source) (audio near3 enhanc\$4) and ((transistor or FET) and (heat adj source)) (differential adj amplifier (differential adj amplifier) and ((transistor or FET) and (heat adj source)) ((differential adj amplifier) and ((transistor or FET) and (heat adj source))) ((differential adj amplifier) and ((transistor or FET) and (heat adj source))) and (audio or sound or enhanc\$4) ((differential adj amplifier adj component\$) (differential adj amplifier adj component\$) and (dual adj transistor\$4) (differential adj amplifier adj component\$) and transistor\$4 (sound near enhanc\$4)	USOCR USPAT; EPO; JPO; DERWENT; USOCR USPAT; EPO; JPO; DERWENT

50	2	((differential adj amplifier adj component\$) and transistor\$4) and heat\$4	USPAT; EPO; JPO; DERWENT;	2004/01/08 17:04
51	1553	(transistor or MOS) and (heat adj source)	USOCR USPAT; EPO; JPO;	2004/01/08 17:07
52	0	(sound near enhanc\$4) and ((transistor or MOS) and (heat adj source))	DERWENT; USOCR USPAT; EPO; JPO;	2004/01/08 17:09
53	1	audio adj enhanc\$4 adj apparatus	DERWENT; USOCR USPAT; EPO; JPO;	2004/01/08 17:11
54	77	audio adj enhanc\$4	DERWENT; USOCR USPAT; EPO; JPO;	2004/01/08 17:11
55	0	(differential adj amplifier adj component\$) and (dual adj transistor\$)	DERWENT; USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:12
56	416	(dual adj transistor\$)	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:12
57	83	(differential adj amplifier) and ((dual adj transistor\$))	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:12
58	16	((differential adj amplifier) and ((dual adj transistor\$))) and (heat or heated or heater or heating)	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:12
59	О		USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:17
60	12	(((differential adj amplifier) and ((dual adj transistor\$))) and (heat or heated or heater or heating)) and temperature	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:15
61	2659	solid adj state adj component\$	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:30
62	4143835	61and (heat or heated or heater or heating)	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:16
64	966	(solid adj state adj component\$) and heat\$4	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:17
65	256	((solid adj state adj component\$) and heat\$4) and enhanc\$4	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:17
66	29	(solid adj state adj component\$) and (heat adj source)	USOCR USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:23

67	307	(solid adj state adj component\$) and (circuit adj board)	USPAT; EPO; JPO;	2004/01/08 17:24
68	24		DERWENT; USOCR USPAT;	2004/01/08 17:24
		board)) and sound	EPO; JPO; DERWENT; USOCR	!
69	173	((solid adj state adj component\$) and heat\$4) and (circuit adj board)	USPAT; EPO; JPO; DERWENT;	2004/01/08 17:24
70	12	(((solid adj state adj component\$) and heat\$4) and (circuit adj board)) and sound	USOCR USPAT; EPO; JPO; DERWENT;	2004/01/08 17:28
71	50	sound adj quality adj enhanc\$4	USOCR USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:28
72	2	(sound adj quality adj enhanc\$4) and (solid adj state adj component\$)	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:29
74	0	((sound adj quality adj enhanc\$4) and transistor) and heat\$4	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:29
75	0	((sound adj quality adj enhanc\$4) and transistor) and temperature	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:29
73	3	(sound adj quality adj enhanc\$4) and transistor	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:29
76	0	(heat adj source) near (solid adj state adj component\$)	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:33
77	0	(heat adj source) near (solid adj state adj components)	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:31
78	3	heat near (solid adj state adj components)	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:31
79	26	(heat adj source) near (transistor or CMOS or (dual adj transistor))	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:35
80	30	(heat adj source) near (transistor or transistors or CMOS or (dual adj transistors))	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:34
81	2	((heat adj source) near (transistor or transistors or CMOS or (dual adj transistors))) and (audio or sound)	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:34
83	4	(heat adj source) near (transistors or CMOS)	USPAT; EPO; JPO; DERWENT; USOCR	2004/01/08 17:35

82	26	(heat adj source) near (transistor or CMOS)	USPAT;	2004/01/08 17:36
			EPO; JPO;	
			DERWENT;	
			USOCR	